NSN 5961-00-299-4975

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-299-4975
Inclosure Material:
Metal
Overall Length:
Between 1.439 inches and 1.573 inches
Overall Height:
0.450 inches
Overall Width:
1.050 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case and quality assurance level tx
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
Between 7.50 amperes source cutoff current and 20.00 amperes source cutoff current
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead and 1 case
Specification Data:
81349-mil-s-19500/456 government specification

Unit Of Measure:

N/a

Shelf Life:

NSN 5961-00-299-4975

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0